## NSN 5962-01-377-2580

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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Flight control e/i fscm 76823
Features Provided:
Bipolar and programmed and tested to mil-std-883
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Product Name:
Microcircuit-nws dtack pal
Voltage Rating And Type Per Characteristic:
-1.5 volts absolute input and 12.0 volts absolute input
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Special Features:
Nuclear hardness critical items
Nuclear Hardness Critical Feature:
Hardened
Terminal Type And Quantity:
20 printed circuit
Departure From Cited Designator:
Altered by programming & marking
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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